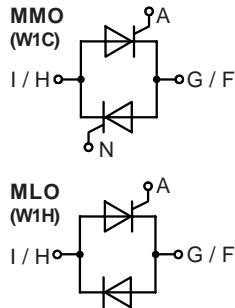


AC Controller Modules

$I_{RMS} = 175 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

Preliminary Data

V_{RSM} V_{DSM}	V_{RRM} V_{DRM}	Type
800	800	MMO 175-08io7
1200	1200	MMO 175-12io7
1600	1600	MMO 175-16io7
		MLO 175-08io7
		MLO 175-12io7
		MLO 175-16io7



Symbol	Conditions	Maximum Ratings	
I_{RMS}	$T_C = 85^\circ\text{C}, 50 - 400 \text{ Hz, (per single controller)}$	175	A
I_{TRMS}		125	A
I_{TAVM}	$T_C = 85^\circ\text{C}; 180^\circ \text{ sine}$	80	A
I_{TSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	1500	A
	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	1600	A
I^2t	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0$	1350	A
	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	1450	A
$(di/dt)_{cr}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	11200	A^2s
	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	10750	A^2s
$(di/dt)_{cr}$	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0$	9100	A^2s
	$t = 10 \text{ ms (50 Hz), sine}$ $t = 8.3 \text{ ms (60 Hz), sine}$	8830	A^2s
$(dv/dt)_{cr}$	$T_{VJ} = 125^\circ\text{C}$ $f = 50 \text{ Hz, } t_p = 200 \mu\text{s}$	150	$\text{A}/\mu\text{s}$
	$V_D = \frac{2}{3} V_{DRM}$ $I_G = 0.45 \text{ A}$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = 125^\circ\text{C}; V_{DR} = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty; \text{method 1 (linear voltage rise)}$	1000	$\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = 125^\circ\text{C}$ $I_T = I_{TAVM}$	10	W
	$t_p = 30 \mu\text{s}$ $t_p = 300 \mu\text{s}$	5	W
P_{GAVM}		0.5	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+150	$^\circ\text{C}$
		150	$^\circ\text{C}$
		-40...+125	$^\circ\text{C}$
V_{ISOL}	$50/60 \text{ Hz, RMS}$ $I_{ISOL} \leq 1 \text{ mA}$	2500	V_\sim
	$t = 1 \text{ min}$ $t = 1 \text{ s}$	3000	V_\sim
M_d	Mounting torque (M4)	1.5...2.0/14...18	Nm/lb.in.
Weight	typ.	18	g

Data according to IEC 60747 and to a single thyristor/diode unless otherwise stated.

Features

- Thyristor controller for AC (circuit W1C acc. to IEC) for mains frequency
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Lead suitable for PC board solering

Applications

- Switching and control of single and three phase AC circuits
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling
- High power density
- Small and light weight

Symbol	Conditions	Characteristic Values		
I_D, I_R	$T_{VJ} = 125^\circ C; V_R = V_{RRM}; V_D = V_{DRM}$	\leq	5	mA
V_T	$I_T = 200 A; T_{VJ} = 25^\circ C$	\leq	1.57	V
V_{TO}	For power-loss calculations only	0.85	V	
r_T		3.7	mΩ	
V_{GT}	$V_D = 6 V$	$T_{VJ} = 25^\circ C$	\leq	1.5 V
		$T_{VJ} = -40^\circ C$	\leq	1.6 V
I_{GT}	$V_D = 6 V$	$T_{VJ} = 25^\circ C$	\leq	100 mA
		$T_{VJ} = -40^\circ C$	\leq	200 mA
V_{GD}	$T_{VJ} = 125^\circ C; V_D = \frac{2}{3} V_{DRM}$	\leq	0.2 V	
I_{GD}		\leq	10 mA	
I_L	$T_{VJ} = 25^\circ C; t_p = 10 \mu s$	\leq	450	mA
	$I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$			
I_H	$T_{VJ} = 25^\circ C; V_D = 6 V; R_{GK} = \infty$	\leq	200	mA
t_{gd}	$T_{VJ} = 25^\circ C; V_D = \frac{1}{2} V_{DRM}$	\leq	2	μs
	$I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$			
R_{thJC}	per thyristor; DC	0.5	K/W	
	per module	0.25	K/W	
R_{thCH}	per thyristor; sine 180° el	typ.	0.12 K/W	
	per module	typ.	0.06 K/W	
d_s	Creeping distance on surface	11.2	mm	
d_a	Creepage distance in air	17.0	mm	
a	Max. allowable acceleration	50	m/s ²	

Dimensions in mm (1 mm = 0.0394")

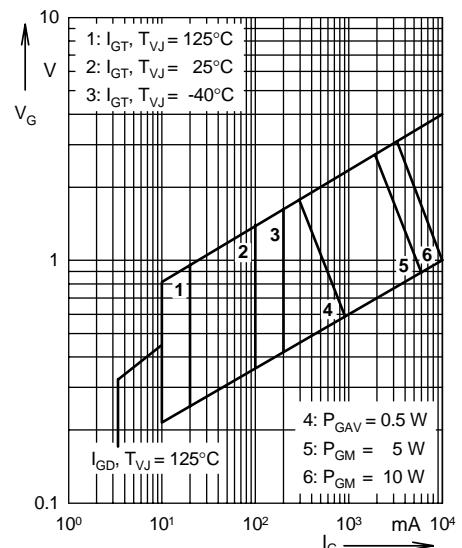
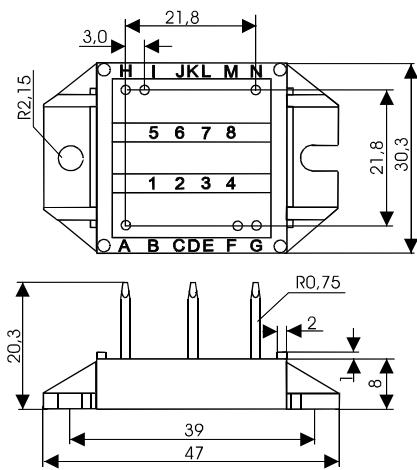


Fig. 1 Gate trigger characteristics

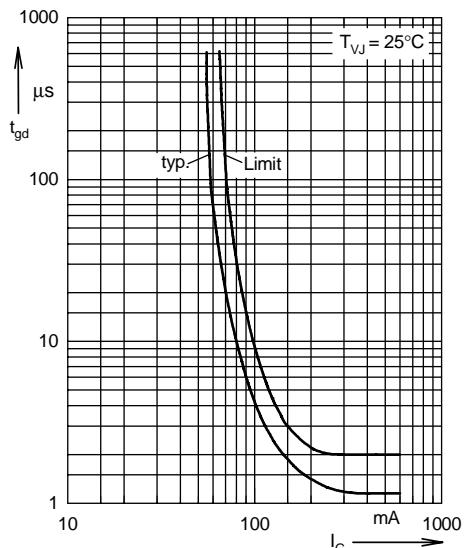


Fig. 2 Gate trigger delay time